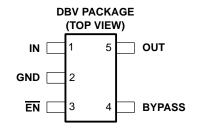
SLVS299B - SEPTEMBER 2000 - REVISED MAY 2001

- 50-mA Low-Dropout Regulator
- Available in 1.5-V, 1.8-V, 2.5-V, 2.8-V, 3.0-V
- Output Noise Typically 56 μV<sub>RMS</sub> (TPS79030)
- Only 17 μA Quiescent Current at 50 mA
- 1 μA Quiescent Current in Standby Mode
- Dropout Voltage Typically 57 mV at 50 mA (TPS79030)
- Over Current Limitation
- -40°C to 125°C Operating Junction Temperature Range
- 5-Pin SOT-23 (DBV) Package

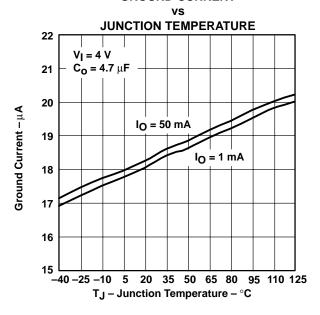
#### description

The TPS790xx family of low-dropout (LDO) voltage regulators offers the benefits of low-dropout voltage, ultralow-power operation, low-output noise, and miniaturized packaging. These regulators feature low-dropout voltages and ultralow quiescent current compared to conventional LDO regulators. An internal resistor, in conjunction with an external bypass capacitor, creates a low-pass filter to reduce the noise. The TPS79030 exhibits only 56 μV<sub>RMS</sub> of output voltage noise using 0.01 μF bypass and 10 μF output capacitors. Offered in a 5-terminal small outline integrated-circuit SOT-23 package, the TPS790xx series devices are ideal for micropower operations, low output noise, and where board space is limited.

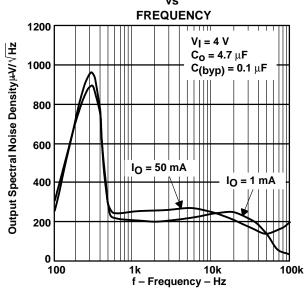
The usual PNP pass transistor has been replaced by a PMOS pass element. Because the PMOS pass element behaves as a low-value resistor, the dropout voltage is very low, typically 57 mV at 50 mA of load current (TPS79030), and is directly proportional to the load current. The quiescent current is ultralow (17  $\mu$ A typically) and is stable over the entire range of output load current (0 mA to 50 mA). Intended for use in portable systems such as laptops and cellular phones, the ultralow-dropout voltage feature and ultralow-power operation result in a significant increase in system battery operating life.



TPS79030 GROUND CURRENT



## TPS78930 OUTPUT SPECTRAL NOISE DENSITY





Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



SLVS299B - SEPTEMBER 2000 - REVISED MAY 2001

#### description (continued)

The TPS790xx also features a logic-enabled sleep mode to shut down the regulator, reducing quiescent current to 1  $\mu$ A typical at T<sub>J</sub> = 25°C. The TPS790xx is offered in 1.5 V, 1.8 V, 2.5 V, 2.8 V, 3.0 V.

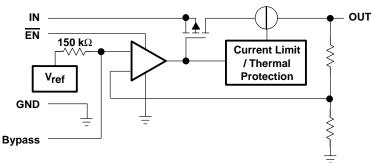
#### **AVAILABLE OPTIONS**

TJ	VOLTAGE	PACKAGE	PART N	SYMBOL	
	1.5 V		TPS79015DBVT†	TPS79015DBVR‡	PEBI
	1.8 V	007.00	TPS79018DBVT†	TPS79018DBVR‡	PECI
–40°C to 125°C	2.5 V	2.5 V SOT-23 (DBV)	TPS79025DBVT†	TPS79025DBVR‡	PEDI
	2.8 V	(557)	TPS79028DBVT <sup>†</sup>	TPS79028DBVR <sup>‡</sup>	PEEI
	3.0 V		TPS79030DBVT†	TPS79030DBVR‡	PEFI

<sup>†</sup>The DBVT indicates tape and reel of 250 parts.

#### functional block diagram

#### TPS79015/18/25/28/30



#### **Terminal Functions**

TERMI	TERMINAL		DESCRIPTION
NAME	NO.	1/0	DESCRIPTION
BYPASS	4	I	Bypass
EN	3	_	Enable input
GND	2		Ground
IN	1	ı	Input supply voltage
OUT	5	0	Regulated output voltage

<sup>&</sup>lt;sup>‡</sup>The DBVR indicates tape and reel of 3000 parts.

SLVS299B - SEPTEMBER 2000 - REVISED MAY 2001

#### detail description

The TPS790xx uses a PMOS pass element to dramatically reduce both dropout voltage and supply current over more conventional PNP-pass-element LDO designs. The PMOS pass element is a voltage-controlled device and, unlike a PNP transistor, it does not require increased drive current as output current increases. Supply current in the TPS790xx is essentially constant from no load to maximum load.

The TPS790xx family of low-dropout (LDO) regulators have been optimized for use in battery-operated equipment. They feature extremely low dropout voltages, low output noise, low quiescent current (17  $\mu$ A typically), and enable inputs to reduce supply currents to 1  $\mu$ A when the regulators are turned off.

The internal voltage reference is a key source of noise in a LDO regulator. The TPS790xx has a BYPASS pin which is connected to the voltage reference through a 150-k $\Omega$  internal resistor. The 150-k $\Omega$  internal resistor, in conjunction with an external bypass capacitor connected to the BYPASS pin, creates a low pass filter to reduce the voltage reference noise and, therefore, the noise at the regulator output. Note that the output will start up slower as the bypass capacitance increases due to the RC time constant at the bypass pin that is created by the internal 150-k $\Omega$  resistor and external capacitor.

Current limiting and thermal protection prevent damage by excessive output current and/or power dissipation. The device switches into a constant-current mode at approximately 350 mA; further load reduces the output voltage instead of increasing the output current. The thermal protection shuts the regulator off if the junction temperature rises above approximately 165°C. Recovery is automatic when the junction temperature drops approximately 25°C below the high temperature trip point. The PMOS pass element includes a back gate diode that conducts reverse current when the input voltage level drops below the output voltage level.

A voltage of 1.7 V or greater on the EN input will disable the TPS790xx internal circuitry, reducing the supply current to 1  $\mu$ A. A voltage of less than 0.9 V on the  $\overline{\text{EN}}$  input will enable the TPS790xx and will enable normal operation to resume. The  $\overline{\text{EN}}$  input does not include any deliberate hysteresis, and it exhibits an actual switching threshold of approximately 1.5 V.

#### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Input voltage range (see Note 1)	0.3 V to 13.5 V
Voltage range at EN	$-0.3 \text{ V to V}_{\text{I}} + 0.3 \text{ V}$
Voltage on OUT, FB	
Peak output current	Internally limited
ESD rating, HBM	
Continuous total power dissipation	See Dissipation Rating Table
Operating virtual junction temperature range, T <sub>.J</sub>	–40°C to 150°C
Storage temperature range, T <sub>stg</sub>	–65°C to 150°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: All voltage values are with respect to network ground terminal.

#### DISSIPATION RATING TABLE

BOARD	PACKAGE	$R_{ heta}$ JC	$R_{ heta JA}$	DERATING FACTOR ABOVE T <sub>A</sub> = 25°C	$T_{\mbox{$A$}} \leq 25^{\circ}\mbox{$C$}$ POWER RATING	T <sub>A</sub> = 70°C POWER RATING	T <sub>A</sub> = 85°C POWER RATING
Low K <sup>‡</sup>	DBV	65.8 °C/W	259 °C/W	3.9 mW/°C	386 mW	212 mW	154 mW
High K§	DBV	65.8 °C/W	180 °C/W	5.6 mW/°C	555 mW	305 mW	222 mW

<sup>‡</sup> The JEDEC Low K (1s) board design used to derive this data was a 3 inch x 3 inch, two layer board with 2 ounce copper traces on top of the board. § The JEDEC High K (2s2p) board design used to derive this data was a 3 inch x 3 inch, multilayer board with 1 ounce internal power and ground planes and 2 ounce copper traces on top and bottom of the board.



SLVS299B - SEPTEMBER 2000 - REVISED MAY 2001

#### recommended operating conditions

	MIN	NOM MAX	UNIT
Input voltage, V <sub>I</sub> (see Note 2)	2.7	10	V
Continuous output current, IO (see Note 3)	0	50	mA
Operating junction temperature, TJ	-40	125	°C

- NOTES: 2. To calculate the minimum input voltage for your maximum output current, use the following formula:  $V_I(min) = V_O(max) + V_{DO}$  (max load)
  - 3. Continuous output current and operating junction temperature are limited by internal protection circuitry, but it is not recommended that the device operate under conditions beyond those specified in this table for extended periods of time.

### electrical characteristics ove<u>r re</u>commended operating free–air temperature range, $V_I = V_{O(typ)} + 1$ V, $I_O = 1$ mA, $\overline{EN} = 0$ V, $C_o = 4.7$ $\mu F$ (unless otherwise noted)

PARAMETER		TEST COI	NDITIONS	MIN	TYP	MAX	UNIT	
	TPS79015	T <sub>J</sub> = 25°C,	2.7 V < V <sub>I</sub> < 10 V		1.5			
	173/9013	$T_J = -40^{\circ}\text{C} \text{ to } 125^{\circ}\text{C},$	2.7 V < V <sub>I</sub> < 10 V	1.455		1.545		
	TPS79018	T <sub>J</sub> = 25°C,	2.8 V < V <sub>I</sub> < 10 V		1.8			
	125/9018	$T_J = -40^{\circ}C \text{ to } 125^{\circ}C,$	2.8 V < V <sub>I</sub> < 10 V	1.746		1.854		
Output voltage (10 μA to 50 mA load)	TPS79025	T <sub>J</sub> = 25°C,	3.5 V < V <sub>I</sub> < 10 V		2.5		V	
(see Note 4)	17379025	$T_J = -40^{\circ}C \text{ to } 125^{\circ}C,$	3.5 V < V <sub>I</sub> < 10 V	2.425		2.575	V	
	TPS79028	T <sub>J</sub> = 25°C,	3.8 V < V <sub>I</sub> < 10 V		2.8			
	173/9020	$T_J = -40^{\circ}C \text{ to } 125^{\circ}C,$	3.8 V < V <sub>I</sub> < 10 V	2.716		2.884		
	TPS79030	T <sub>J</sub> = 25°C,	4.0 V < V <sub>I</sub> < 10 V		3			
	11-37-9030	$T_J = -40^{\circ}\text{C to } 125^{\circ}\text{C},$	4.0 V < V <sub>I</sub> < 10 V	2.910		3.090		
Quiescent current (GND current) (see Note	EN = 0 V, T <sub>J</sub> = 25°C	$10 \mu A < I_O < 50 mA$ ,		17		^		
Quiescent current (GND current) (see Note	<del>+</del> )	EN = 0  V, T <sub>J</sub> = -40°C to 125°C	I <sub>O</sub> = 50 mA,			28	μА	
Load regulation		EN = 0 V, T <sub>J</sub> = 25°C	$I_{O} = 10 \mu A \text{ to } 50 \text{ mA},$		8		mV	
Output voltage line regulation ( $\Delta V_O/V_O$ )		$V_{O} + 1 V < V_{I} \le 10 V$	T <sub>J</sub> = 25°C		0.04			
(see Notes 4 and 5)	$V_O + 1 V < V_I \le 10 V$ , $T_J = -40^{\circ}C \text{ to } 125^{\circ}C$				0.1	%/V		
Output noise voltage (TPS79030)	BW = 300 Hz to 50 kH $C_0 = 10 \mu F$ , $I_0 = 50$	z, $C_{\text{(byp)}} = 0.01 \mu\text{F},$ mA, $T_{\text{J}} = 25^{\circ}\text{C}$		56		μVrms		
Output current limit	$V_{O} = 0 V,$	See Note 4		350	750	mA		
Standby current		EN = V <sub>I</sub> ,	2.7 < V <sub>I</sub> < 10 V		1		μΑ	
Standby current		$T_J = -40^{\circ}\text{C} \text{ to } 125^{\circ}\text{C}$				2	μΑ	

NOTES: 4. The minimum IN operating voltage is 2.7 V or V<sub>O</sub> (typ) + 1 V, whichever is greater. The maximum IN voltage is 10 V. The minimum output current is 10 μA and the maximum output current is 50 mA.

5. If  $V_0 \le 1.8 \text{ V then } V_{1min} = 2.7 \text{ V}$ ,  $V_{1max} = 10 \text{ V}$ :

Line Reg. (mV) = 
$$(\%/V) \times \frac{V_O(V_{lmax} - 2.7 V)}{100} \times 1000$$

If  $V_O \ge 2.5 \text{ V}$  then  $V_{lmin} = V_O + 1 \text{ V}$ ,  $V_{lmax} = 10 \text{ V}$ :

Line Reg. (mV) = 
$$(\%/V) \times \frac{V_O(V_{Imax} - (V_O + 1 V))}{100} \times 1000$$



SLVS299B - SEPTEMBER 2000 - REVISED MAY 2001

# electrical characteristics ove<u>r re</u>commended operating free–air temperature range, V<sub>I</sub> = V<sub>O(typ)</sub> + 1 V, I<sub>O</sub> = 1 mA, $\overline{\text{EN}}$ = 0V, C<sub>o</sub> = 4.7 $\mu\text{F}$ (unless otherwise noted) (continued)

PARAMETER		TEST	MIN	TYP	MAX	UNIT	
High level enable input voltage		2.7 V < V <sub>I</sub> < 10 V		1.7			V
Low level enable input voltage		2.7 V < V <sub>I</sub> < 10 V				0.9	V
Power supply ripple rejection (TPS79030	f = 1 kHz, T <sub>J</sub> = 25°C,	C <sub>O</sub> = 10 μF, C <sub>(byp)</sub> = 0.01 μF		85		dB	
Input current (FNI)		EN = 0 V		-1	0	1	μΑ
Input current (EN)		EN = V <sub>I</sub>		-1		1	μΑ
Dropout voltage (see Note 6)	TPS79028	$I_{O} = 50 \text{ mA},$	T <sub>J</sub> = 25°C		60		
Dropout voltage (see Note 6)	17379020	I <sub>O</sub> = 50 mA,	$T_J = -40^{\circ}\text{C to } 125^{\circ}\text{C}$			125	mV
Dropout voltage (see Note 6)	TPS79030	$I_{O} = 50 \text{ mA},$	T <sub>J</sub> = 25°C		57	·	IIIV
Diopout voltage (see Note 6)	17379030	$I_{O} = 50 \text{ mA},$	T <sub>J</sub> = -40°C to 125°C			115	

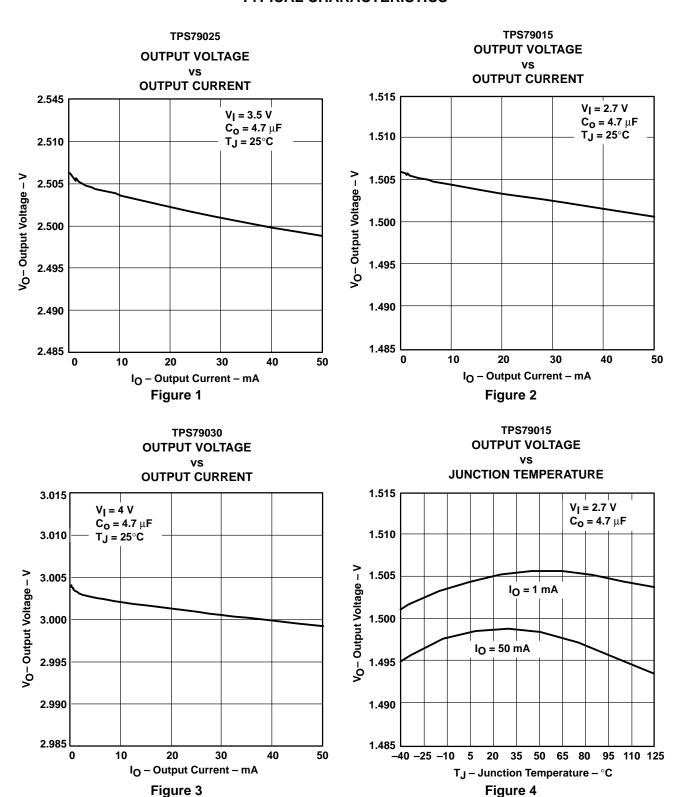
IN voltage equals V<sub>O</sub>(typ) –100 mV; The TPS79030 output voltage is set to 2.9 V. The TPS79015, TPS79018, and TPS79025 dropout voltage is limited by input voltage range limitations.

#### TYPICAL CHARACTERISTICS

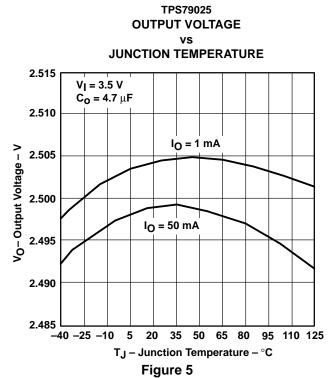
#### **Table of Graphs**

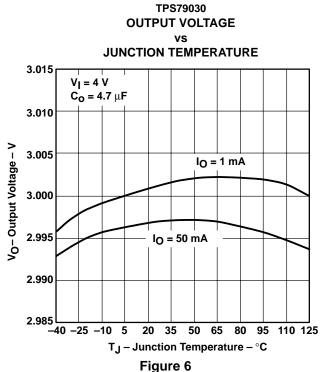
			FIGURE
V	Output valtage	vs Output current	1, 2, 3
۷o	Output voltage	vs Junction temperature	4, 5, 6
	Ground current	vs Junction temperature	7
	Output spectral noise density	vs Frequency	8 – 10
	Root mean squared output noise	vs Bypass capacitance	11
Z <sub>o</sub>	Output impedance	vs Frequency	12
$V_{DO}$	Dropout voltage	vs Junction temperature	13
	Ripple rejection	vs Frequency	14 – 16
٧o	Output voltage, enable voltage	vs Time (start-up)	17 – 19
	Line transient response		20, 22
	Load transient response		21, 23
	Equivalent series resistance (ESR)	vs Output current	24, 25

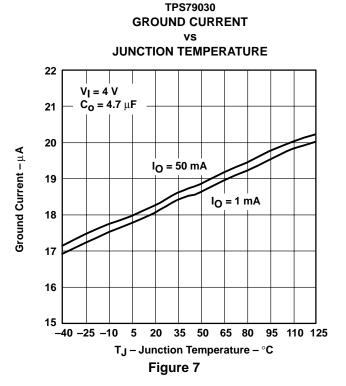


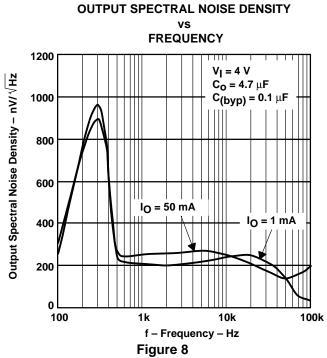




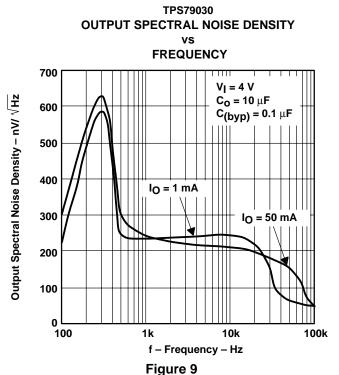


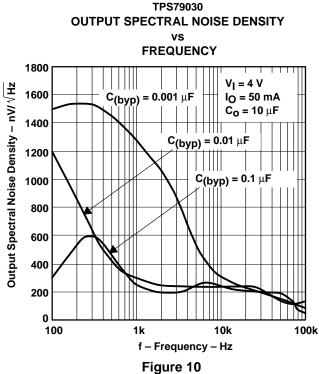




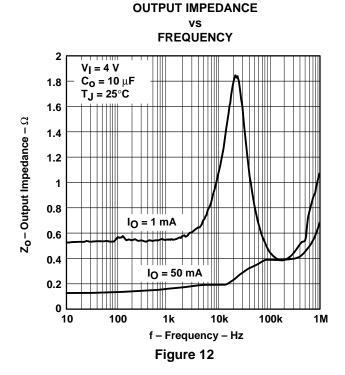


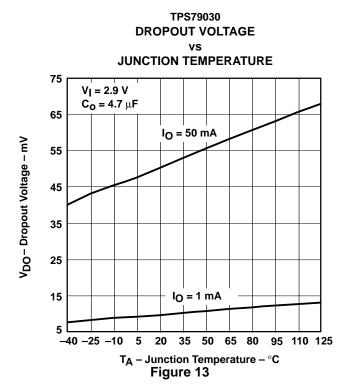
**TPS79030** 

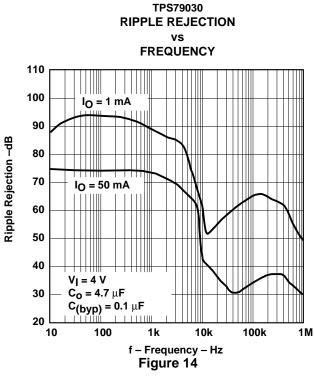


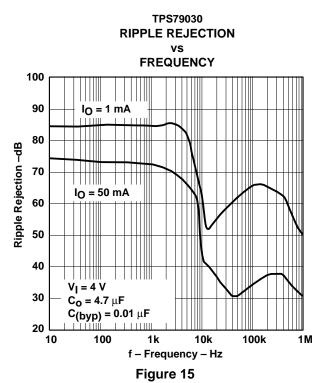


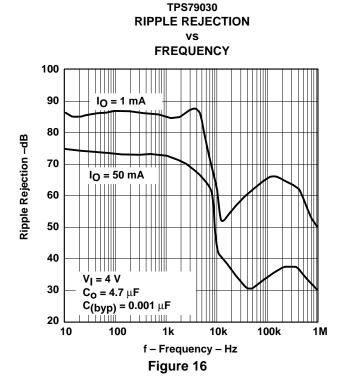
#### **ROOT MEAN SQUARED OUTPUT NOISE BYPASS CAPACITANCE** 300 RMS – Root Mean Squared Output Noise – $\mu$ V(RMS) $C_0 = 10 \mu F$ 250 200 150 V<sub>O</sub> = 3 V 100 50 V<sub>O</sub> = 1.5 V 0.00001 0.0001 0.001 0.01 $C_{(bypass)}$ – Bypass Capacitance – $\mu F$ Figure 11



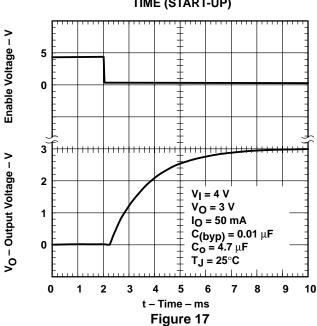


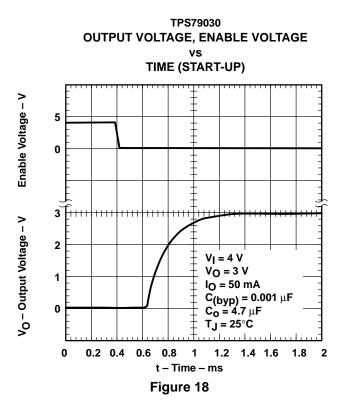


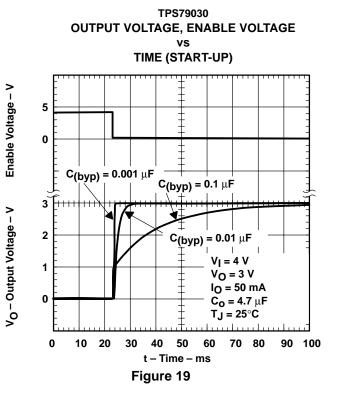


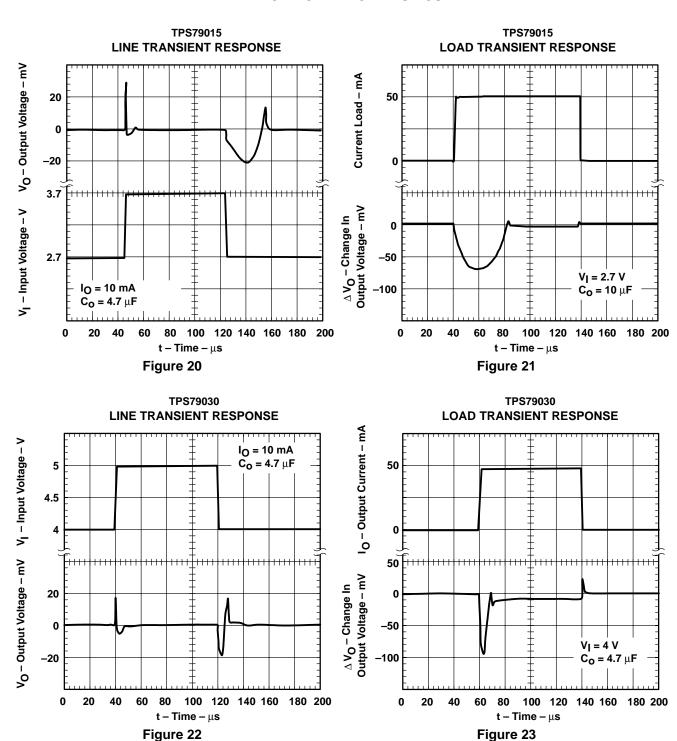


**TPS79030 OUTPUT VOLTAGE, ENABLE VOLTAGE** TIME (START-UP)











**TPS79030** 

SLVS299B - SEPTEMBER 2000 - REVISED MAY 2001

#### **TYPICAL CHARACTERISTICS**

#### TYPICAL REGIONS OF STABILITY **EQUIVALENT SERIES RESISTANCE (ESR) OUTPUT CURRENT** 100 V<sub>I</sub> = 4 V ESR – Equivalent Series Resistance – $\Omega$ $C_0 = 4.7 \mu F$ $V_0 = 3 V$ Region of Instability 10 **Region of Stability** 0.1 5 10 25 30 35 40 45 50 IO - Output Current - mA

TYPICAL REGIONS OF STABILITY **EQUIVALENT SERIES RESISTANCE (ESR) OUTPUT CURRENT** 100  $V_I = 4 V$ ESR – Equivalent Series Resistance –  $\Omega$  $C_0 = 10 \mu F$  $V_0 = 3 V$ Region of Instability 10 Region of Stability 5 10 25 30 35 40 45 0 IO - Output Current - mA Figure 25

**TPS79030** 

TEXAS INSTRUMENTS
POST OFFICE BOX 655303 • DALLAS, TEXAS 75265

SLVS299B - SEPTEMBER 2000 - REVISED MAY 2001

#### **APPLICATION INFORMATION**

The TPS790xx family of low-dropout (LDO) regulators have been optimized for use in battery-operated equipment. They feature extremely low dropout voltages, low quiescent current (17  $\mu$ A typically), and enable inputs to reduce supply currents to less than 1  $\mu$ A when the regulators are turned off.

A typical application circuit is shown in Figure 26.

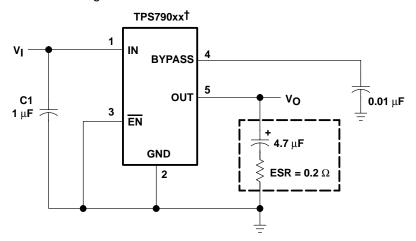


Figure 26. Typical Application Circuit

#### external capacitor requirements

Although not required, a 0.047- $\mu$ F or larger ceramic input bypass capacitor, connected between IN and GND and located close to the TPS790xx, is recommended to improve transient response and noise rejection. A higher-value electrolytic input capacitor may be necessary if large, fast-rise-time load transients are anticipated and the device is located several inches from the power source.

Like all low dropout regulators, the TPS790xx requires an output capacitor connected between OUT and GND to stabilize the internal control loop. The minimum recommended capacitance is 4.7  $\mu F$ . The ESR (equivalent series resistance) of the capacitor should be between 0.2  $\Omega$  and 10  $\Omega$  to ensure stability. Capacitor values larger than 4.7  $\mu F$  are acceptable, and allow the use of smaller ESR values. Capacitances less than 4.7  $\mu F$  are not recommended because they require careful selection of ESR to ensure stability. Solid tantalum electrolytic, aluminum electrolytic, and multilayer ceramic capacitors are all suitable, provided they meet the requirements described above. Most of the commercially available 4.7  $\mu F$  surface-mount solid tantalum capacitors, including devices from Sprague, Kemet, and Nichico, meet the ESR requirements stated above. Multilayer ceramic capacitors may have very small equivalent series resistances and may thus require the addition of a low value series resistor to ensure stability.

#### **CAPACITOR SELECTION**

PART NO.	MFR.	VALUE	MAX ESR†	SIZE $(H \times L \times W)^{\dagger}$
T494B475K016AS	KEMET	4.7 μF	1.5 Ω	$1.9\times3.5\times2.8$
195D106x0016x2T	SPRAGUE	10 μF	1.5 Ω	$1.3\times7.0\times2.7$
695D106x003562T	SPRAGUE	10 μF	1.3 Ω	$2.5\times7.6\times2.5$
TPSC475K035R0600	AVX	4.7 μF	0.6 Ω	$2.6\times6.0\times3.2$

<sup>†</sup> Size is in mm. The ESR maximum resistance is in Ohms at 100 kHz and T<sub>A</sub> = 25°C. Contact the manufacturer for the minimum ESR values.



SLVS299B - SEPTEMBER 2000 - REVISED MAY 2001

#### **APPLICATION INFORMATION**

#### external capacitor requirements (continued)

The external bypass capacitor, used in conjunction with an internal resistor to form a low-pass filter, should be a low ESR ceramic capacitor. For example, the TPS79030 exhibits only  $56\,\mu\text{V}_{RMS}$  of output voltage noise using a 0.01  $\mu\text{F}$  ceramic bypass capacitor and a10  $\mu\text{F}$  ceramic output capacitors. Note that the output will start up slower as the bypass capacitance increases due to the RC time constant at the bypass pin that is created by the internal 150 k $\Omega$  resistor and external capacitor.

#### power dissipation and junction temperature

Specified regulator operation is assured to a junction temperature of  $125^{\circ}$ C; the maximum junction temperature should be restricted to  $125^{\circ}$ C under normal operating conditions. This restriction limits the power dissipation the regulator can handle in any given application. To ensure the junction temperature is within acceptable limits, calculate the maximum allowable dissipation,  $P_{D(max)}$ , and the actual dissipation,  $P_D$ , which must be less than or equal to  $P_{D(max)}$ .

The maximum-power-dissipation limit is determined using the following equation:

$$P_{D(max)} = \frac{T_J max - T_A}{R_{\theta,JA}}$$

Where:

T<sub>J</sub>max is the maximum allowable junction temperature.

 $R_{\theta,JA}$  is the thermal resistance junction-to-ambient for the package, see the dissipation rating table.

T<sub>A</sub> is the ambient temperature.

The regulator dissipation is calculated using:

$$P_D = (V_I - V_O) \times I_O$$

Power dissipation resulting from quiescent current is negligible. Excessive power dissipation will trigger the thermal protection circuit.

#### regulator protection

The TPS790xx PMOS-pass transistor has a built-in back diode that conducts reverse current when the input voltage drops below the output voltage (e.g., during power down). Current is conducted from the output to the input and is not internally limited. If extended reverse voltage operation is anticipated, external limiting might be appropriate.

The TPS790xx features internal current limiting and thermal protection. During normal operation, the TPS790xx limits output current to approximately 350 mA. When current limiting engages, the output voltage scales back linearly until the overcurrent condition ends. While current limiting is designed to prevent gross device failure, care should be taken not to exceed the power dissipation ratings of the package. If the temperature of the device exceeds approximately 165°C, thermal-protection circuitry shuts it down. Once the device has cooled down to below approximately 140°C, regulator operation resumes.

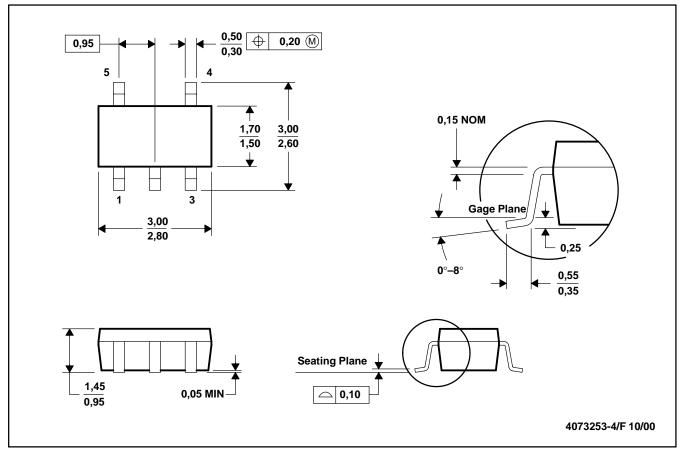


SLVS299B - SEPTEMBER 2000 - REVISED MAY 2001

#### **MECHANICAL DATA**

#### DBV (R-PDSO-G5)

#### **PLASTIC SMALL-OUTLINE**



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion.
- D. Falls within JEDEC MO-178

www.ti.com

23-May-2025

#### PACKAGING INFORMATION

Orderable part number	erable part number Status Material type Package   Pins I		Package qty   Carrier	RoHS	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)	
TD070045DD\/D	A .:	5 1	007.00 (DD) () 1.5	0000 11 4005 700		(4)	(5)	10.1.105	DED!
TPS79015DBVR	Active	Production	SOT-23 (DBV)   5	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PEBI
TPS79015DBVR.A	Active	Production	SOT-23 (DBV)   5	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PEBI
TPS79015DBVT	Active	Production	SOT-23 (DBV)   5	250   SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PEBI
TPS79015DBVT.A	Active	Production	SOT-23 (DBV)   5	250   SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PEBI
TPS79018DBVR	Active	Production	SOT-23 (DBV)   5	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PECI
TPS79018DBVR.A	Active	Production	SOT-23 (DBV)   5	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PECI
TPS79018DBVT	Active	Production	SOT-23 (DBV)   5	250   SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PECI
TPS79018DBVT.A	Active	Production	SOT-23 (DBV)   5	250   SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PECI
TPS79025DBVR	Active	Production	SOT-23 (DBV)   5	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PEDI
TPS79025DBVR.A	Active	Production	SOT-23 (DBV)   5	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PEDI
TPS79025DBVT	Active	Production	SOT-23 (DBV)   5	250   SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PEDI
TPS79025DBVT.A	Active	Production	SOT-23 (DBV)   5	250   SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PEDI
TPS79028DBVR	Active	Production	SOT-23 (DBV)   5	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PEEI
TPS79028DBVR.A	Active	Production	SOT-23 (DBV)   5	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PEEI
TPS79028DBVT	Active	Production	SOT-23 (DBV)   5	250   SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PEEI
TPS79028DBVT.A	Active	Production	SOT-23 (DBV)   5	250   SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PEEI
TPS79030DBVR	Active	Production	SOT-23 (DBV)   5	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PEFI
TPS79030DBVR.A	Active	Production	SOT-23 (DBV)   5	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PEFI
TPS79030DBVT	Active	Production	SOT-23 (DBV)   5	250   SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PEFI
TPS79030DBVT.A	Active	Production	SOT-23 (DBV)   5	250   SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PEFI

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

<sup>(2)</sup> **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.



#### **PACKAGE OPTION ADDENDUM**

www.ti.com 23-May-2025

(4) Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.



#### TAPE AND REEL INFORMATION



# TAPE DIMENSIONS + K0 - P1 - B0 W Cavity - A0 -

		Dimension designed to accommodate the component width
		Dimension designed to accommodate the component length
		Dimension designed to accommodate the component thickness
	W	Overall width of the carrier tape
Г	P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



\*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS79015DBVR	SOT-23	DBV	5	3000	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TPS79015DBVT	SOT-23	DBV	5	250	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TPS79018DBVR	SOT-23	DBV	5	3000	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TPS79018DBVT	SOT-23	DBV	5	250	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TPS79025DBVR	SOT-23	DBV	5	3000	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TPS79025DBVT	SOT-23	DBV	5	250	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TPS79028DBVR	SOT-23	DBV	5	3000	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TPS79028DBVT	SOT-23	DBV	5	250	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TPS79030DBVR	SOT-23	DBV	5	3000	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TPS79030DBVT	SOT-23	DBV	5	250	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3





\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS79015DBVR	SOT-23	DBV	5	3000	182.0	182.0	20.0
TPS79015DBVT	SOT-23	DBV	5	250	182.0	182.0	20.0
TPS79018DBVR	SOT-23	DBV	5	3000	182.0	182.0	20.0
TPS79018DBVT	SOT-23	DBV	5	250	182.0	182.0	20.0
TPS79025DBVR	SOT-23	DBV	5	3000	182.0	182.0	20.0
TPS79025DBVT	SOT-23	DBV	5	250	182.0	182.0	20.0
TPS79028DBVR	SOT-23	DBV	5	3000	182.0	182.0	20.0
TPS79028DBVT	SOT-23	DBV	5	250	182.0	182.0	20.0
TPS79030DBVR	SOT-23	DBV	5	3000	182.0	182.0	20.0
TPS79030DBVT	SOT-23	DBV	5	250	182.0	182.0	20.0

#### IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2025. Texas Instruments Incorporated